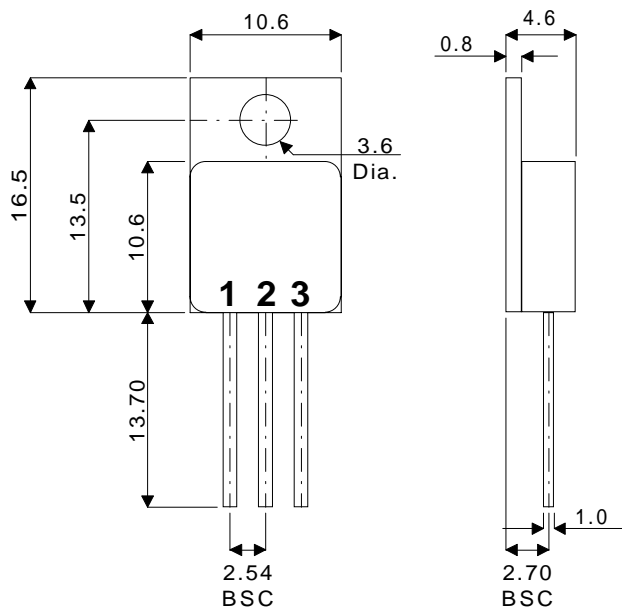


**MECHANICAL DATA**

Dimensions in mm



**DUAL SCHOTTKY  
 BARRIER DIODE IN  
 TO220 METAL PACKAGE  
 FOR HI-REL APPLICATIONS**

**FEATURES**

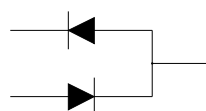
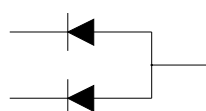
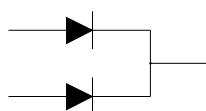
- HERMETIC TO220 METAL PACKAGE
- ISOLATED CASE
- SCREENING OPTIONS AVAILABLE
- OUTPUT CURRENT 30A
- LOW  $V_F$
- LOW LEAKAGE

**TO220 METAL PACKAGE**

**Common Cathode**  
**SB30-100M**

**Common Anode**  
**SB30-100AM**

**Series Connection**  
**SB30-100RM**



1 = A<sub>1</sub> Anode 1  
 2 = K Cathode  
 3 = A<sub>2</sub> Anode 2

1 = K<sub>1</sub> Cathode 1  
 2 = A Anode  
 3 = K<sub>2</sub> Cathode 2

1 = K<sub>1</sub> Cathode 1  
 2 = Centre Tap  
 3 = A<sub>2</sub> Anode

**ABSOLUTE MAXIMUM RATINGS** ( $T_{case} = 25^{\circ}C$  unless otherwise stated)

		SB30-100M SB30-100AM SB30-100RM
$V_{RRM}$	Peak Repetitive Reverse Voltage	100V
$V_{RSM}$	Peak Non-Repetitive Reverse Voltage	100V
$V_R$	Continuous Reverse Voltage	100V
$I_O$	Output Current	30A
$I_{FSM}$	Peak Non-Repetitive Surge Current (50Hz)	245A
$T_{STG}$	Storage Temperature Range	-55°C to 150°C
$T_J$	Maximum Operating Junction Temperature	150°C/W

**ELECTRICAL CHARACTERISTICS** (Per Diode)( $T_{CASE} = 25^{\circ}C$  unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_F$ Forward Voltage	$I_F = 16.5A$ $T_J = 150^{\circ}C$			1.0	V
	$I_F = 33A$ $T_J = 25^{\circ}C$			1.3	
$I_R$ Reverse Current	$V_R = V_{RRM}$ $T_J = 150^{\circ}C$			30	mA
	$V_R = V_{RRM}$			500	$\mu A$
$C_d$ Junction Capacitance	$V_R = 5 V$ $f = 1 MHz$		500		pF

Pulse test  $t_p=300\mu s$        $\delta \leq 2\%$

Parameter		Unit
$R_{TH(j-a)}$ Maximum Thermal Resistance Junction To Case	both diodes 1.4 per diode 2.3	$^{\circ}C/W$
$R_{TH(j-c)}$ Maximum Thermal Resistance Junction To Case	1.3	$^{\circ}C/W$